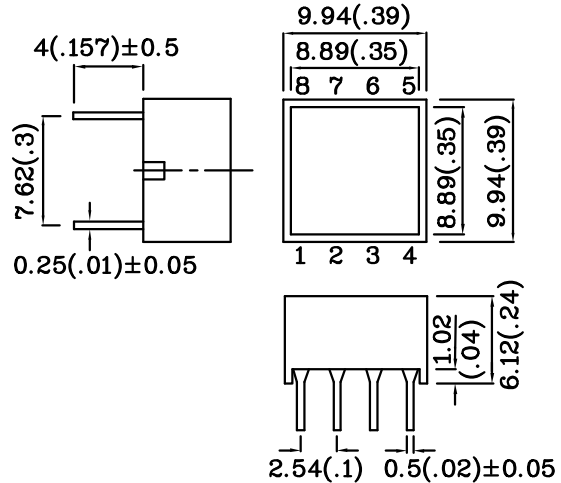
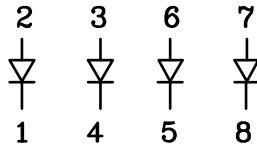


Features

- UNIFORM LIGHT EMITTING AREA.
- LOW CURRENT OPERATION.
- EASILY MOUNTED ON P.C. BOARDS.
- FLUSH MOUNTABLE.
- EXCELLENT ON/OFF CONTRAST.
- CAN BE USED WITH PANELS AND LEGEND MOUNTS.
- RoHS COMPLIANT.



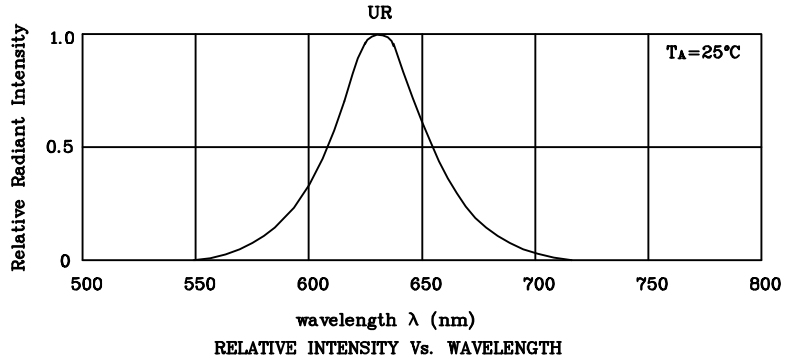
Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is ± 0.25(0.01") unless otherwise noted.

Absolute maximum ratings (TA=25°C)		UR (GaAsP/GaP)	Unit
Reverse voltage	V _R	5	V
Forward current	I _F	30	mA
Forward current (peak) 1/10Duty cycle 0.1ms pulse width	i _{FS}	160	mA
Power dissipation	P _T	105	mW
Operating temperature	T _A	-40 ~ +85	°C
Storage temperature	T _{stg}	-40 ~ +85	
Lead solder temperature [5mm below package base]	260°C For 5 Seconds		

Operating Characteristics (TA=25°C)		UR (GaAsP/GaP)	Unit
Forward voltage (typ.) (I _F =20mA)	V _F	2.0	V
Forward voltage (max.) (I _F =20mA)	V _F	2.5	V
Reverse current (V _R =5V)	I _R	10	uA
Wavelength at peak emission (I _F =20mA)	λ peak	627	nm
Wavelength of Dominant emission (I _F =20mA)	λ D	625	nm
Spectral Line half-width (I _F =20mA)	Δλ	45	nm
Capacitance (V _F =0V, f=1MHz)	C	15	pF

Part Number	Emitting Color	Emitting Material	Lens-color	Luminous Intensity (I _F =20mA) mcd		Wavelength
				min.	typ.	nm λ P
XEUR2655M	Red	GaAsP/GaP	White Diffused	10	59	627
Published Date : MAR 05,2005 Drawing No :XDSA1967 V3 Checked : Shin Chi P.1/2						



❖ UR

